

Description

The RHK003N06 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a

 $\label{eq:Battery protection or in other Switching application.}$



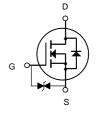
SOT-23

General Features

 $V_{DS} = 60V I_{D} = 0.3A$

 $R_{DS(ON)} < 2\Omega$ @ $V_{GS}=10V$

ESD Rating: HBM≥2000V



N-Channel MOSFET

Application

Battery protection

Load switch

Uninterruptible power supply

Package Marking and Ordering Information

| Product ID | Pack | Brand | Qty(PCS) |
|------------|--------|------------|----------|
| RHK003N06 | SOT-23 | HXY MOSFET | 3000 |

Absolute Maximum Ratings (T_C=25°Cunless otherwise noted)

| Symbol | Parameter | Limit | Unit | |
|----------------------------------|--|----------------------|------------|--------------|
| V _{DS} | Drain-Source Voltage | | 60 | V |
| V _G S | Gate-Source Voltage | | ±20 | V |
| | | T _A =25℃ | 0.3 | |
| l _D | Continuous Drain Current (T _J =150°C) | T _A =100℃ | 0.19 | Α |
| I DM | Drain Current-Pulsed (Note 1) | | 0.8 | Α |
| P _D | Maximum Power Dissipation | | 0.35 | W |
| T _J ,T _{STG} | Operating Junction and Storage Temperature Range | | -55 To 150 | $^{\circ}$ C |
| Reja | Thermal Resistance,Junction-to-Ambient (Note 2) | | 350 | °C/W |



Electrical Characteristics (T_A=25 ℃unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|----------------------------------|---------------------|---|-----|------|------|------|
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250µA | 60 | 68 | - | V |
| Zero Gate Voltage Drain Current | IDSS | V _{DS} =60V,V _{GS} =0V | - | - | 1 | μΑ |
| Gate-Body Leakage Current | Igss | V _{GS} =±10V,V _{DS} =0V | - | ±100 | ±500 | nA |
| | | V _{GS} =±20V,V _{DS} =0V | - | ±4 | ±10 | uA |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} ,I _D =250μA | 0.7 | 1.2 | 1.9 | V |
| | | V _{GS} =5V, I _D =0.1A | - | 1.3 | 3 | Ω |
| Drain-Source On-State Resistance | Rds(on) | V _{GS} =10V, I _D =0.1A | - | 1 | 2 | Ω |
| Forward Transconductance | grs | V _{DS} =10V,I _D =0.2A | 0.1 | - | - | S |
| Input Capacitance | C _{lss} | | - | 21 | 50 | PF |
| Output Capacitance | Coss | V_{DS} =25V, V_{GS} =0V, F=1.0MHz | - | 11 | 25 | PF |
| Reverse Transfer Capacitance | C _{rss} | 1 - 1.0IVII 12 | - | 4.2 | 5 | PF |
| Turn-on Delay Time | td(on) | | - | 10 | - | nS |
| Turn-on Rise Time | t _r | V _{DD} =30V,I _D =0.2A | - | 50 | - | nS |
| Turn-Off Delay Time | td(off) | V _{GS} =10V,R _{GEN} =10Ω | - | 17 | - | nS |
| Turn-Off Fall Time | t _f | | - | 10 | - | nS |
| | | V _{DS} =10V,I _D =0.3A, | | | | |
| Total Gate Charge | Qg | V _{GS} =4.5V | - | 1.7 | 3 | nC |
| Diode Forward Voltage (Note 3) | VsD | V _{GS} =0V,I _S =0.2A | - | - | 1.2 | V |
| Diode Forward Current (Note 2) | Is | | - | - | 0.3 | Α |

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



Typical Electrical And Thermal Characteristics

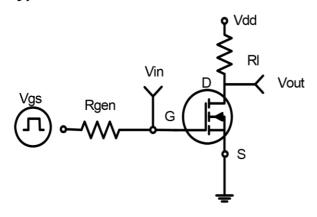


Figure 1:Switching Test Circuit

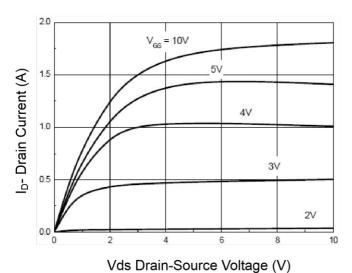


Figure 3 Output Characteristics

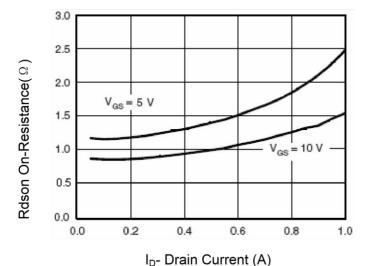


Figure 5 Drain-Source On-Resistance

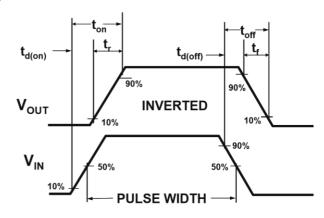


Figure 2:Switching Waveforms

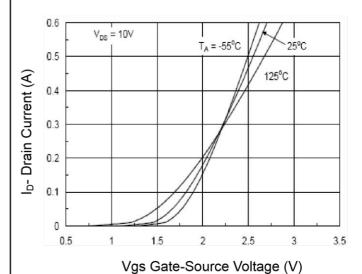
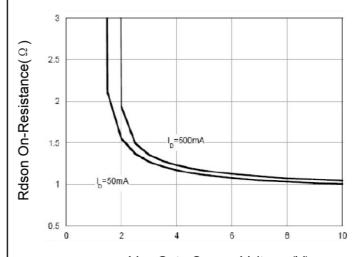
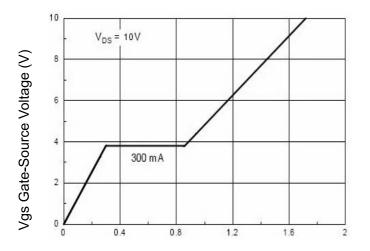


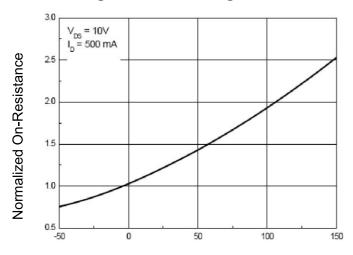
Figure 4 Transfer Characteristics



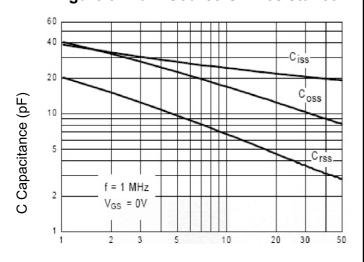
Vgs Gate-Source Voltage (V)
Figure 6 Rdson vs Vgs



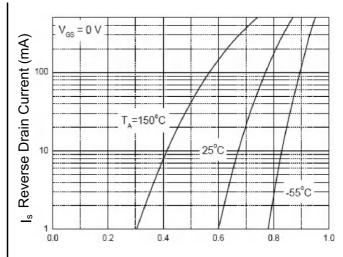
Qg Gate Charge (nC) Figure 7 Gate Charge



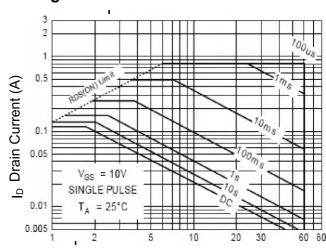
 T_J -Junction Temperature(${}^{\circ}C$)
Figure 9 Drain-Source On-Resistance



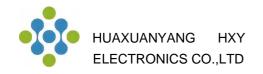
Vds Drain-Source Voltage (V)
Figure 11 Capacitance vs Vds



Vsd Source-Drain Voltage (V)
Figure 8 Source-DrainDiode Forward



Vds Drain-Source Voltage (V)
Figure 10 Safe Operation Area



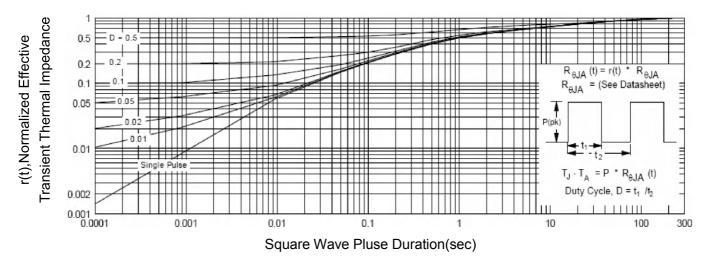
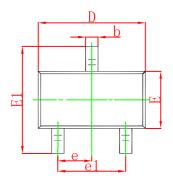
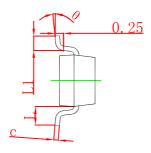


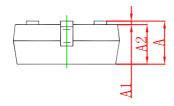
Figure 12 Normalized Maximum Transient Thermal Impedance



SOT-23 Package Outline Dimensions

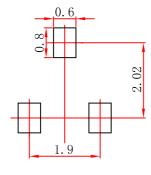






| Symbol | Dimensions In Millimeters | | Dimensions In Inches | | |
|--------|---------------------------|-------|----------------------|-------|--|
| | Min | Max | Min | Max | |
| Α | 0.900 | 1.150 | 0.035 | 0.045 | |
| A1 | 0.000 | 0.100 | 0.000 | 0.004 | |
| A2 | 0.900 | 1.050 | 0.035 | 0.041 | |
| b | 0.300 | 0.500 | 0.012 | 0.020 | |
| С | 0.080 | 0.150 | 0.003 | 0.006 | |
| D | 2.800 | 3.000 | 0.110 | 0.118 | |
| E | 1.200 | 1.400 | 0.047 | 0.055 | |
| E1 | 2.250 | 2.550 | 0.089 | 0.100 | |
| е | 0.950 | TYP | 0.037 TYP | | |
| e1 | 1.800 | 2.000 | 0.071 | 0.079 | |
| L | 0.550 | REF | 0.022 REF | | |
| L1 | 0.300 | 0.500 | 0.012 | 0.020 | |
| θ | 0° | 8° | 0° | 8° | |

SOT-23 Suggested Pad Layout



- Note:
 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.
 3.The pad layout is for reference purposes only.

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DMN2080UCB4-7 DMN61D9UWQ-13 US6M2GTR DMN31D5UDJ-7 DMP22D4UFO-7B DMN1006UCA6-7 DMN16M9UCA6-7
STF5N65M6 IRF40H233XTMA1 STU5N65M6 DMN6022SSD-13 DMN13M9UCA6-7 DMTH10H4M6SPS-13 DMN2990UFB-7B
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BXP4N65F AOL1454G WMJ80N60C4 BXP2N20L BXP2N65D BXT1150N10J BXT1700P06M TSM60NB380CP ROG RQ7L055BGTCR
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